NSN 5961-01-227-1948

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-227-1948 **Inclosure Material:** Metal **Overall Length:** 1.000 inches **Terminal Length:** 0.125 inches **Overall Diameter:** 0.625 inches **Component Name And Quantity:** 16 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode **Voltage Rating In Volts Per Characteristic:** 50.0 reverse voltage, instantaneous all semiconductor device diode **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Precious Material And Location:** External surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 16 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0